

DESCRIPTION

The SDD450 consists of a Photo Darlington transistor optically coupled to a light emitting diode. Optical coupling between the input LED and output Photo Darlington allows for high isolation levels while maintaining low-level DC signal control capability. The SDD450 provides an optically isolated method of controlling many interface applications such as telecommunications, industrial control and instrumentation circuitry.

FEATURES

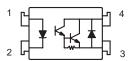
- High current transfer ratio (CTR:MIN 600%)
- High input-to-output isolation voltage (3,750 Vrms)
- Ultra-miniature 4 pin SOP package
- High Load Voltage (Vceo = 300V MIN)

OPTIONS/SUFFIXES*

-TR Tape and Reel

NOTE: Suffixes listed above are not included in marking on device for part number identification.

SCHEMATIC DIAGRAM



- 1. Anode
- 2. Cathode
- 3. Emitter
- 4. Collector

APPLICATIONS

- Home Appliances
- Office Automation Equipment
- Telecom / Datacom
- Power Supplies
- Fax / Modems

ABSOLUTE MAXIMUM RATINGS*

PARAMETER	UNIT	MIN	TYP	MAX
Storage Temperature	°C	-40		125
Operating Temperature	°C	-40		100
Continuous Input Current	mA			50
Transient Input Current	Α			1
Reverse Input Control Voltage	V			6
Output Power Dissipation	mW			170

^{*}The values indicated are absolute stress ratings. Functional operation of the device is not implied at these or any conditions in excess of those defined in electrical characteristics section of this document. Exposure to Absolute Ratings may cause permanent damage to the device and may adversely affect reliability.

APPROVALS

UL / C-UL Approved, File #E201932





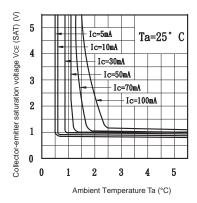
ELECTRICAL CHARACTERISTICS - 25°C

PARAMETER	UNIT	MIN	TYP	MAX	TEST CONDITIONS
INPUT SPECIFICATIONS					
Input Forward Voltage	V		1.2	1.4	If =10mA
Peak Forward Voltage	V			3.5	Ifm = 0.5A
Reverse Current	μΑ			10	Vr =4V
Terminal Capacitance	рF		30		V = 0, f = 1KHz
OUTPUT SPECIFICATIONS					
Collector-Emitter Breakdown Voltage	V	300			Ic = 10uA
Dark Current	μΑ			1	Vce = 10V, If = 0
Floating Capacitance	рF		0.6	1	Vce = 0V, f = 1.0MHz
Saturation Voltage	V			1	If = 20mA, Ic = 1mA
Current Transfer Ratio	%	600	1600	7500	If = 1mA, Vce = 2V
Rise Time	μS		60	300	Ic = 2mA, Vce = 2V, RL = 100 ohms
Fall Time	μS		50	250	Ic = 2mA, Vce = 2V, RL = 100 ohms
COUPLED SPECIFICATIONS					
Isolation Voltage	V	3750			T = 1 minute
Isolation Resistance	GΩ	50			
Cut-off Frequency	kH z		7		Ic = 2mA, Vcc = 5V, RL = 100 ohms

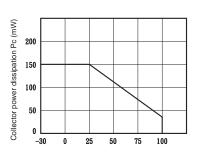
PERFORMANCE DATA

SDD450

Collector-Emitter Saturation Voltage vs. Forward Current N = 100, Ambient Temperature = 25°C

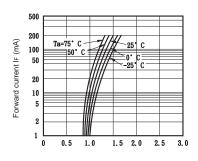


SDD450 Collector Power Dissipation vs. Ambient Temperature N = 100



Ambient temperature Ta (°C)

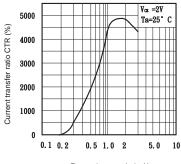
SDD450 Forward Current vs. Forward Voltage N = 100, Ambient Temperature = 25°C



Forward voltage VF (V)

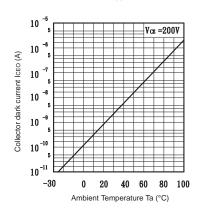
SDD450

Current Transfer Ratio vs. Forward Current N = 100, Ambient Temperature = 25°C

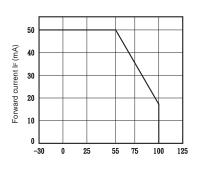


Forward current IF (mA)

SDD450 Collector Dark Current vs. Ambient Temperature N = 100



SDD450 Forward Current vs. Ambient Temperature

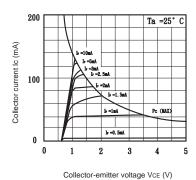


Ambient temperature Ta (°C)

PERFORMANCE DATA

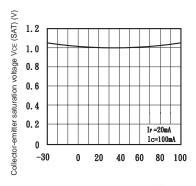
SDD450

Collector Current vs. Collector-Emitter Voltage N = 100, Ambient Temperature = 25°C



SDD450

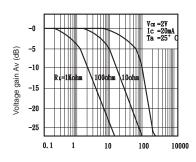
Collector-Emitter Saturation Voltage vs. Ambient Temperature N = 100



Ambient Temperature Ta (°C)

SDD450

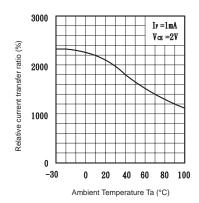
Frequency Response N = 100, Ambient Temperature = 25°C



Frequency f (KHz)

SDD450

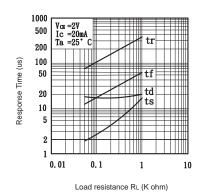
Relative Current Transfer Ratio vs. Ambient Temperature N = 100



SDD450

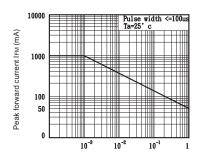
Response Time vs. Load Resistance

N = 100, Ambient Temperature = 25°C



SDD450

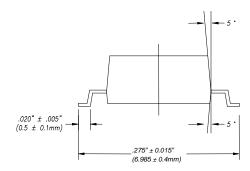
Peak Forward Current vs. Duty Ratio N = 100, Ambient Temperature = 25°C



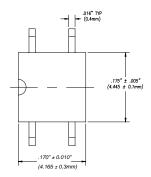
Duty ratio

MECHANICAL DIMENSIONS

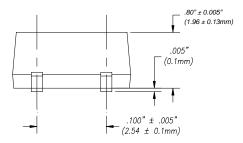
4 PIN SMALL OUTLINE PACKAGE



END VIEW



TOP VIEW



BACK VIEW





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